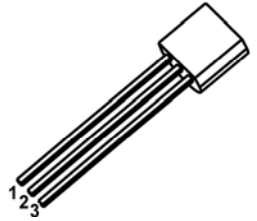
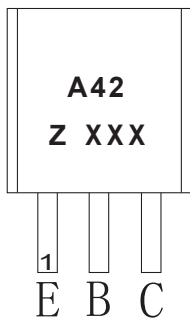


**TO-92 Plastic-Encapsulate Transistors****A42** TRANSISTOR (NPN)**FEATURES**

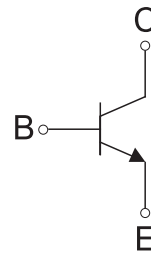
- High voltage

TO-92

1. EMITTER
2. BASE
3. COLLECTOR

**MARKING**

A42=Device code
Z=Rank of h_{FE}
XXX=Code
GXX=Green molding compound device
CXX=Normal molding compound device

Equivalent Circuit**ORDERING INFORMATION**

Part Number	Package	Packing Method	Pack Quantity
A42	TO-92	Bulk	1000pcs/Bag
A42-TA	TO-92	Tape	2000pcs/Box

MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	310	V
V_{CEO}	Collector-Emitter Voltage	305	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current - Continuous	200	mA
I_{CM}	Collector Current - Pulsed	500	mA
P_C	Collector Power Dissipation	625	mW
T_J, T_{stg}	Operation Junction and Storage Temperature Range	-55-150	$^{\circ}\text{C}$
$R_{\theta JA}$	Thermal Resistance, junction to Ambient	200	$^{\circ}\text{C} / \text{W}$

ELECTRICAL CHARACTERISTICS

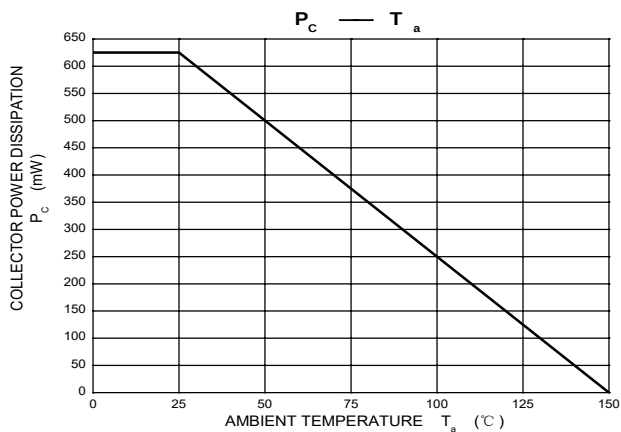
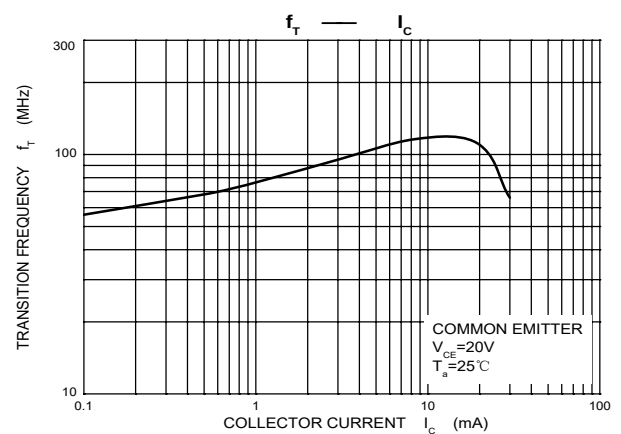
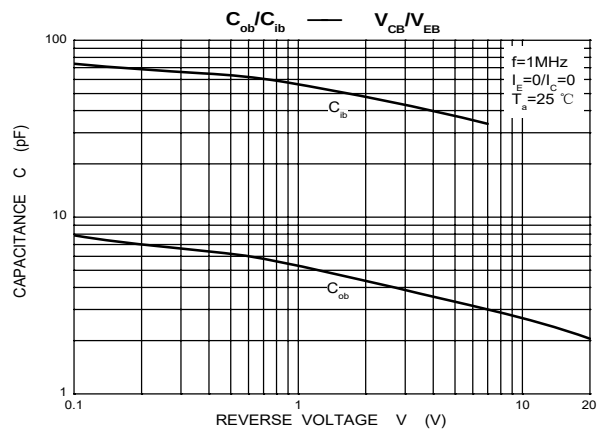
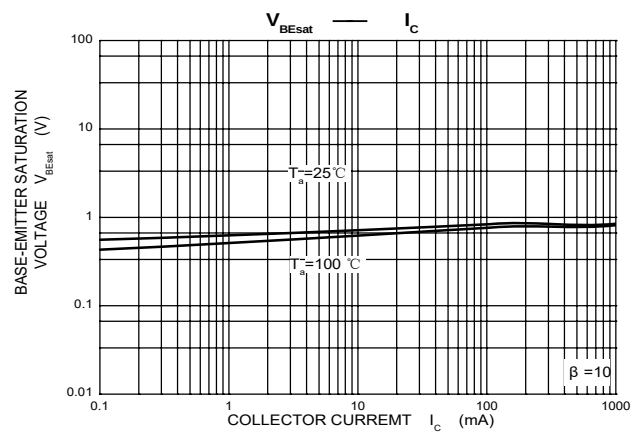
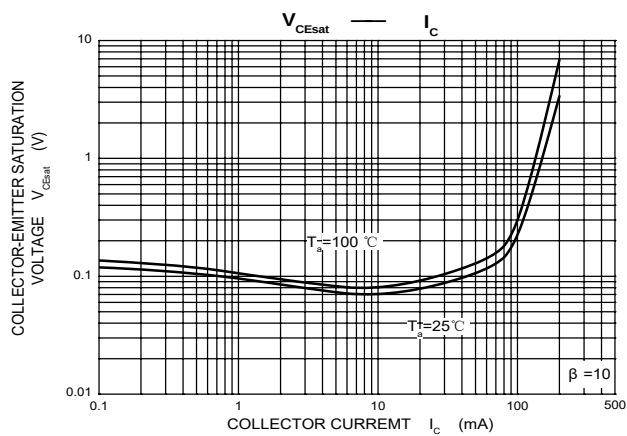
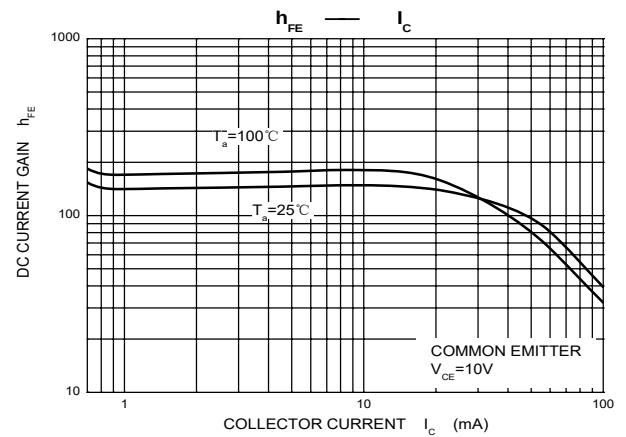
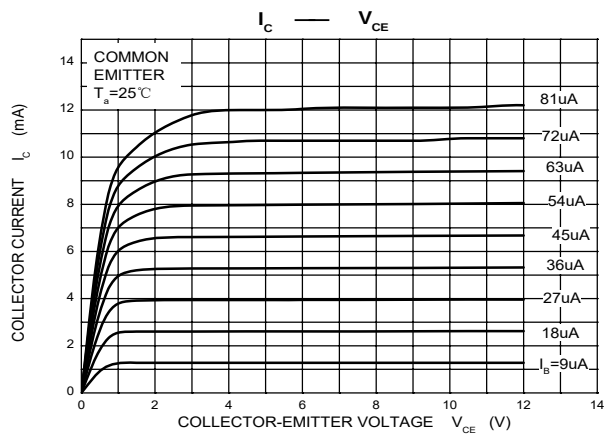
$T_a = 25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = 100\mu\text{A}$, $I_E = 0$	310			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = 1\text{mA}$, $I_B = 0$	305			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = 100\mu\text{A}$, $I_C = 0$	5			V
Collector cut-off current	I_{CBO}	$V_{CB} = 200\text{V}$, $I_E = 0$			0.25	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = 5\text{V}$, $I_C = 0$			0.1	μA
DC current gain	$h_{FE(1)}$	$V_{CE} = 10\text{V}$, $I_C = 1\text{mA}$	60			
	$h_{FE(2)}$	$V_{CE} = 10\text{V}$, $I_C = 10\text{mA}$	80		250	
	$h_{FE(3)}$	$V_{CE} = 10\text{V}$, $I_C = 30\text{mA}$	75			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 20\text{mA}$, $I_B = 2\text{mA}$			0.2	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = 20\text{mA}$, $I_B = 2\text{mA}$			0.9	V
Transition frequency	f_T	$V_{CE} = 20\text{V}$, $I_C = 10\text{mA}$, $f = 30\text{MHz}$	50			MHz

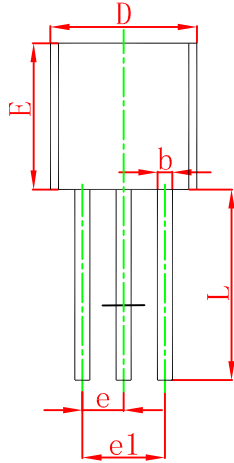
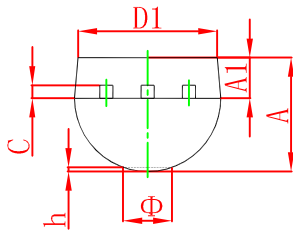
CLASSIFICATION OF $h_{FE(2)}$

Rank	A	B	C
Range	80-100	100-200	200-250

Typical Characteristics

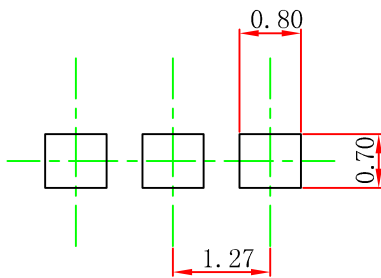


TO-92 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.300	3.700	0.130	0.146
A1	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
c	0.360	0.510	0.014	0.020
D	4.300	4.700	0.169	0.185
D1	3.430		0.135	
E	4.300	4.700	0.169	0.185
e	1.270 TYP		0.050 TYP	
e1	2.440	2.640	0.096	0.104
L	14.100	14.500	0.555	0.571
Φ		1.600		0.063
h	0.000	0.380	0.000	0.015

TO-92 Suggested Pad Layout



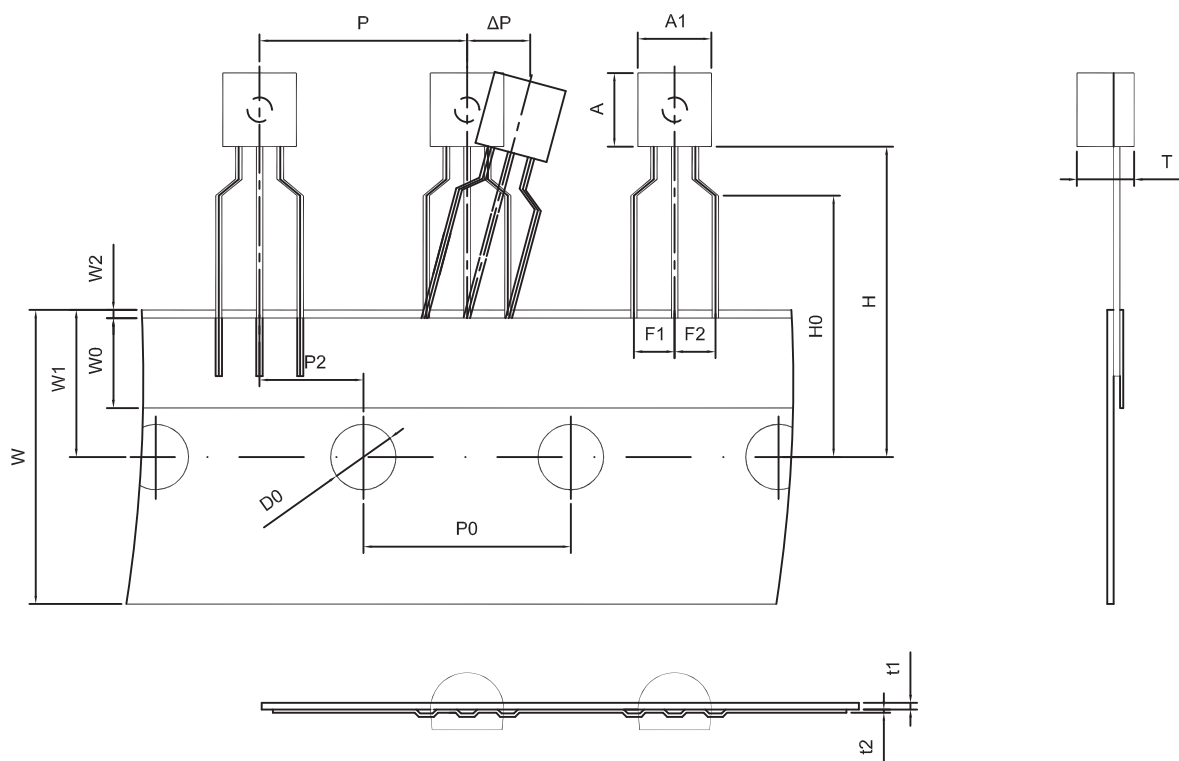
Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

NOTICE

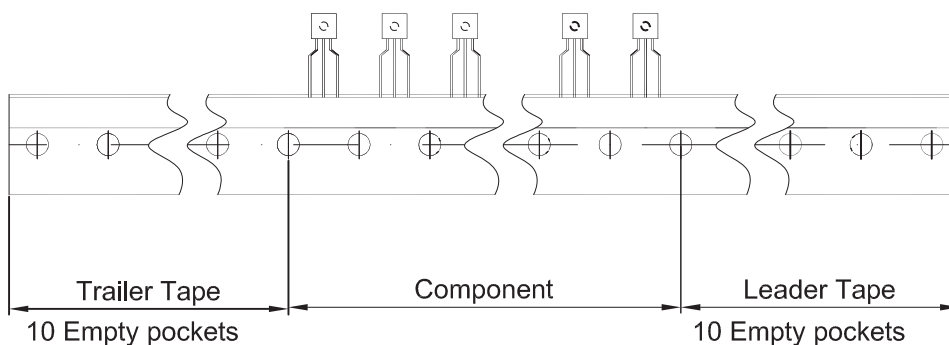
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TO-92 PACKAGE TAPING DIMENSION



Dimiensions are in millimeter

A1	A	T	P	P0	P2	F1	F2	W
4.5	4.5	3.5	12.7	12.7	6.35	2.5	2.5	18.0
W0	W1	W2	H	H0	D0	t1	t2	ΔP
6.0	9.0	1.0 MAX.	19.0	16.0	4.0	0.4	0.2	0



Package	Box	Box Size(mm)	Carton	Carton Size(mm)
TO-92	2000 pcs	333×162×43	20,000 pcs	350×340×250